NSN 5962-01-352-7908



Memory Microcircuit - Page 1 of 2
View Online at https://aerobasegroup.com/nsn/5962-01-352-7908
Overall Height:
0.432 inches
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
170.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
30.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-2.0 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

10.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

250.00 nanoseconds delay

Memory Device Type:

Eprom

Special Features:

Nuclear hardness critical item

NSN 5962-01-352-7908

Memory Microcircuit - Page 2 of 2



Test	Data	Document	ŀ
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0